# **General Purpose Transistor**

# **NPN Silicon**

# BC846BM3T5G, NSVBC846BM3T5G

### Features

- Moisture Sensitivity Level: 1
- ESD Rating: Human Body Model: >4000 V Machine Model: >400 V
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- This is a Pb–Free Device

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	65	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	80	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	100	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR- 5 Board (Note 1) T <sub>A</sub> = 25°C	P <sub>D</sub>	265	mW
Derate above 25°C		2.1	mW/°C
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\thetaJA}$	470	°C/W
Total Device Dissipation Alumina Substrate (Note 2) T <sub>A</sub> = 25°C	P <sub>D</sub>	640	mW
Derate above 25°C		5.1	mW/°C
Thermal Resistance, Junction to Ambient (Note 2)	$R_{\thetaJA}$	195	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

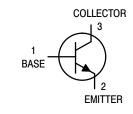
1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

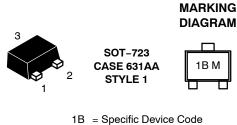
2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.



# **ON Semiconductor®**

### www.onsemi.com





#### 1B = Specific Device Code M = Date Code

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BC846BM3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSVBC846BM3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

 $(I_{C} = 0.2 \text{ mA}, V_{CE} = 5.0 \text{ Vdc}, R_{S} = 2.0 \text{ k}\Omega, f = 1.0 \text{ kHz}, BW = 200 \text{ Hz})$ 

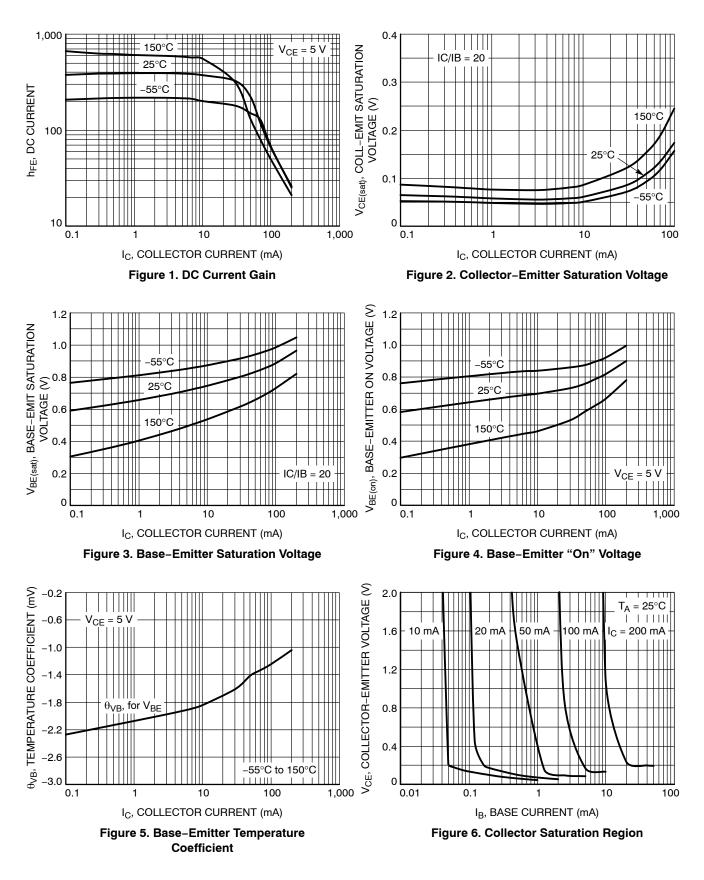
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA)	V <sub>(BR)CEO</sub>	65	_	-	V
Collector – Emitter Breakdown Voltage ( $I_C = 10 \ \mu$ A, V <sub>EB</sub> = 0)	V <sub>(BR)CES</sub>	80	_	-	V
Collector – Base Breakdown Voltage $(I_C = 10 \ \mu A)$	V <sub>(BR)CBO</sub>	80	_	-	V
Emitter – Base Breakdown Voltage ( $I_E = 1.0 \ \mu A$ )	V <sub>(BR)EBO</sub>	6.0	_	-	V
$ \begin{array}{ll} \mbox{Collector Cutoff Current} & (V_{CB}=30\ V) \\ & (V_{CB}=30\ V,\ T_A=150^\circ C) \end{array} $	I <sub>CBO</sub>	-		15 5.0	nA μA
Base Peak Current (t $\leq$ 1 s)	I <sub>BM</sub>	_	_	200	mA
ON CHARACTERISTICS					
DC Current Gain (I <sub>C</sub> = 10 $\mu$ A, V <sub>CE</sub> = 5.0 V) (I <sub>C</sub> = 2.0 mA, V <sub>CE</sub> = 5.0 V)	h <sub>FE</sub>	200	150 290	_ 450	-
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA) (I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5.0 mA)	V <sub>CE(sat)</sub>		_ _	0.25 0.6	V
Base – Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA) (I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5.0 mA)	V <sub>BE(sat)</sub>	-	0.7 0.9	_ _	V
$ \begin{array}{l} \text{Base-Emitter Voltage (I_C = 1.0 mA, V_{CE} = 5.0 \text{ V})} \\ (I_C = 2.0 mA, V_{CE} = 5.0 \text{ V}) \\ (I_C = 10 mA, V_{CE} = 5.0 \text{ V}) \end{array} $	V <sub>BE(on)</sub>	550 580 -	645 660 -	700 700 770	mV
SMALL-SIGNAL CHARACTERISTICS					
$\label{eq:current-Gain-Bandwidth Product} \begin{split} & (I_C = 10 \text{ mA}, \text{ V}_{CE} = 5.0 \text{ Vdc}, \text{ f} = 100 \text{ MHz}) \end{split}$	f <sub>T</sub>	100	-	-	MHz
Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0 MHz)	C <sub>obo</sub>	-	_	4.5	pF
	NF			10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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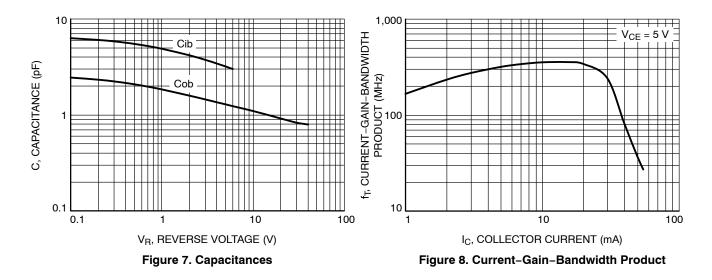
# BC846BM3T5G, NSVBC846BM3T5G

# **TYPICAL CHARACTERISTICS**

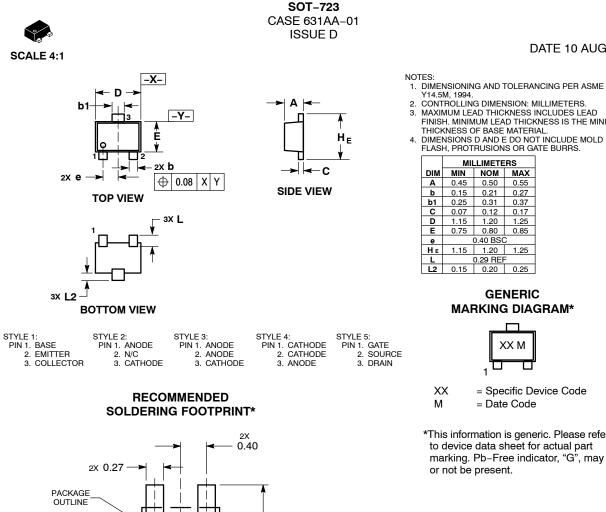


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# **TYPICAL CHARACTERISTICS**







1.50

#### DATE 10 AUG 2009

- THISH. MINIMUM LEAD THICKNESS INCLOSE LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.45	0.50	0.55	
b	0.15	0.21	0.27	
b1	0.25	0.31	0.37	
С	0.07	0.12	0.17	
D	1.15	1.20	1.25	
Е	0.75	0.80	0.85	
е	0.40 BSC			
ΗE	1.15	1.20	1.25	
L	0.29 REF			
L2	0.15	0.20	0.25	

#### GENERIC **MARKING DIAGRAM\***

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= Specific Device Code

= Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

#### \*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

0.36 DIMENSIONS: MILLIMETERS

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